

MINUTES

Minutes of EMC/Power Working Group Meeting, Alcatel Space, 05Nov01
 Ref:
 SPIRE-ALC-MOM-001018

 Issue:
 1.0

 Date:
 06/11/01

 Page:
 1/49

_				m.t ^a Bi	REF.: H-F	P-ASPI-MN-534	
ALCAT	EL	HER	SCHEL/PLA	NCK			
SPACE		F.		N. Antone S. A.	DATE : 0	6/11/01	PAGE : / 🏅
COMPTE REN	DU DE REI	JNION / .	MINUTES OF M	EETING	LIEU / PLAC	CE : Cannes	
OBJET / PURPOSI	Ε:				CLASSIFIC	ATION :	
EMC/POWER	WORKIN	IG GRO	UP MEETING	#12			
				· · · · · · · · · · · · · · · · · · ·		1	
PARTICIPANTS ATTENDEES	S	ociete FIRM	SIGNATURE SIGNATURE	PARTI ATTI	CIPANTS ENDEES	SOCIETE FIRM	SIGNATURE SIGNATURE
SEE N	ext pa	GE FO	2 A COHPLE	TE U	151		
			, <u>,</u> , <u>,</u> , <u>,</u> , , , , , , , , , , ,		2		
REDACTEUR / WRITTEN	N BY :						
CONCLUSION :	- 10 08 - 11 8						-
,							
<u>DISTRIBUTION</u> : PARTICIPANTS /	POUR ACT FOR FURTH	ION : HER ACTION	4				
ATTENDEES	POUR INFO	Ormation Rmation	:				
APPROUVE PAR / APPROVED BY							
NOM / NAME							
SIGNATURE / SIGNATURE							

5

5/11/2001 TEL Grofing PARTICIPANTS. Phone L. TROUGNOU ALCATEL BOB HIBBERD ALCATEL Jackson ESA /ESTEC +31.71 5653526. Bernard +31.71 565 3448 49 7545 8 4539 ESA/ESTEC FILIPRO MARLIANS clemeni Kalde SROW Berl Joost vun Leeuwen +31.30.253.5655 Albert Naber SRON +31.30.253 5600 SRON Nick Whyborn +31.50.363 4074 +34 02.25075332 LABEN HAURIBID MICCOLIS +33 02 25075 237 LABEN PAOLO LEUTENEGGER + 44 1235 44 6046. DOUG GRIFFIN RAL RUSSO FRANCESCO 71.80 208 Francisco Run ALENIA +39 011 +49 89 30 000 3556 Reinhard Katterbher MPE BAX Telence 33 1 63 08 3625 6/11/2001 4 4 VON TEA / Sectary Dominique

AGENDA: SEE ANNEX 1 AUCHTEL TO PRESENT LEL CHARACEERSING TOMORROW TO ALL PARTICIPANTS PLANCK REQUEST A DEDICATEO PLANCK EMC MEETING TO DISCUSS & PEFINE PLANCK RELATED ETIC MODELS PLANCK INSTRUMENTS ARE REQUESTED TO PROVIDE THE AGENDA TOPICS, THE DATE FOR THIS MEETING IS 17TH JANUARY 2002

1/6

(R) REVIEW OF ACTIONS - SEE ANNEXIFOR ACTIONS SUMMARY

AIA: LCL ALLOCATION & SIZING: THE INSTRUMENTS ARE REQUESTED AGAIN TO PROVIDE COMPLETE DATA REGARDING LELS, (LONG PEAK /SHORT PEAK / ANERAGE). THIS DATA TO BE PROVIDED BY 15/11/2001.

AI2: PROVIDE ETIC CONTROL PLAN, SPIRE - CLOSED PACS - TO BE PROVIDED 15/11/01 HIFI - ALREADY PROVIDED. LFI - TO BE PROVIDED ** 15/11/01 HFI -

* SEE ANNEX FOR A SUMMARY OF TESTS.

AI3: LFipresents extracts of diaftEMC Control Plan (trbe issued soon) ESA recalls that for RE testing, wost of the RE is from the harness -> fest at Instrument level would be more significant than just at muit level + analysis at Instrument level. Advice: combine tests at muit level () test at Instrument kvel.

ALCATEL #ESA REMIND THE INSTRUMENTS TO DEFINE HOW THE CS TESTS WILL BE PERFORMUN AT CYRO TE MERATURES WITHIN THE EMC CONTROL PLAN. AZI PROVIDE DE RESISTANCE OF WAVEGUIDES: HIFI STATE THAT THIS DEPENDS UPON THE MATERIAL USED wHICH IS PROVIDED BY ASTRIUM. - ESTIMATED BY HIFI AS 100m. UNLESS A DE BLOCKED WAVEGUIDE IS USED

2/6

- AILL IDENTIFY & PROVIDE ELECTRICAL MODELS FOR CRYO HARNESS, ASTRIUM HAVE PROVIDED THE INFORMATION SEE EMC/ESD ANALYSIS REPORT FOR SDR 150. AS, 1400, TN. 0434 ISSUE 1 8, 3, 89
- AI12 PROVIDE OVERALL GROUNDINE DIAGRAM, ALCATEL IS PREPARINE THIS DIAGRAM.

- NEED & DEFINITION OF PADIATED ETL TESTING AT HERSCHEL "EQM" LEVEL. - SEE ANNEX FOR EXTRACT OF SPIRE, HIFT & PACS NEEDS.

(*) EM(

- Test Gu be done at room T° for HiFi (RATIONALE WILL BE PROVIDED) Notfor SPIRE & PACS (need of cryogenic T°)
- SPIRE Queern: very difficult to do representative RS at Instrument level.

Presentation of the forescen "cryogenic test set up" by C. Kalde from Astrium and discussion about the way to radiate juside the "fest covity".



Nick (SRON) Suggestion is to have rather radiative auteurs inside. Hifi will not use all mixers -> coaxial feedthrought will be available to Gumected internal radiative field and internal probe. (or it would be possible to create a need feedthrough) Glibration would be done with Cryostat open, at room temperature with standard external radiating ankunz.

3/6

4/6 Not the whole fequency band from 14 kHz tr 186Hz is uitereshing to test in this RS Grifgurahlon. (Gruphing through ables, not apertures, dominates up to a certain frequency) ASPI Suggest [200 KHz - 18 GHz], TBC 2 - 18 GHz], for lower frequencics [14kHz -> 200 KHz] RS will be done with an external antenna, in a Standard way, with 21/m.

ASTRIUM PROJECTIED THEIR UNDERSTANDING OF THE EMC TEST CAMPAIENS, SEE ANNEY TIT, ASTRIUM IS CONCERNED ABOUT THE ANTENNA WHICH COULD BE USED IN CRYO, WHAT WOULD BE THE REQUIRENTIONS FOR THESE ANTENNA? ESA ENCOURAGE EMC RS TESTING IS PERFORMED AT EQM LEVEL. ALL INSTRUMENTS WILL PERINE THE REPRESENTION OF THEIR BOM INSTRUMENT WITH RESPECT TO ELECTRICAL/EMC ISSUES. I ALL AT 3 INSTRUMENTS

ASPI/ASTRIUM WILL START DEFINING THE REQUIREMENTS FOR THE TEST ANTENNA TO IDENTIFY ANY PARTICULAR NEEDS FOR THE CRYO TESTS, clarifications on :

- · ICLASS
- · ITRIP
- . I LIMIT
- · I overshoot

THE GOIR WILL BE UPDATED TO REFLECT THESE CLARIFICATIONS.

GROUNDING DIAGRAM

LFI PRESENTED THEIR GROUNDING DIAGRAM SEE ANNEY IV

HEI PRESENTED THEIR GROUNDING CONCEPTS, THE DETECTION CHAIN WILL BE ELECTRICALLY INJULATED FROM STRUCTURE, (SEE ANNEX I) FROM THE 4K BOX TO THE PAU, THE GROUNDING REFERENCE BEING IN THE REU. NEXT CHI / WORKING GROUP MEETING - WEDNESDAY 16TH JAN 2002 AT ALCATEL 09:00 AT ALCATEL 09:00

REF. : H-P-ASPI-MN-534 HERSCHEL/PLANCE ALCATEL SPACE PAGE : 6/6 DATE: 06/11/01 **COMPTE RENDU DE REUNION / MINUTES OF MEETING** LIEU / PLACE : Cannes SUITE / CONTINUED : ACTION Presentation of Cryo - harness Electric requirements ANNEX # VIII (to be sent by email) by LFi. + management of associated thermal Gustraints. -> optimisation. ETLC aspects of cry, harness 2150 presented: Sensitive to external magnetic field because he twishing ! Gucern is HFI 4K cooler Hfield emission. Dy mentions that SST is less fragile for this crys cables.



	v		LISTE D'ACTIONS / AC	CTION ITEM LIST	REF. : H-P-A	SPI-MN-534	
		EL	OBJET / PURPOSE : EMC/POWER WORKING GROUP MEETING #12			DATE : 06/11/2001	
	HERSCHEL/PLANCK			PAGE :			
			ACTION			DATE	
Origine	N°		Description	Responsable /	Responsible	Echéance / Due	
ALCATEL	X	PROVIDE	FREQUENCY PLAN	LFI		15/11/01	
<i>µ</i>	2	40	µ H	HFI		15/11/01	
11	3	DEFINE RE	PRESENTIVITY OF EQMINISTRUMENTS WRT ELEVECTRICAL/EMC	ALL INSTRUME	ints	15/11/01	
				· · · · · · · · · · · · · · · · · · ·			
i 							
· 							
				· · · · · · · · · · · · · · · · · · ·			
	1						
						<u> </u>	



EMC/Power WG meeting #12 Cannes, 5-6 November 2001 AGENDA

Review of actions

Power :

Clarification on LCL characteristics

□ Inrush current (IID-A section 5.9.5.6.4)



- Need and definition of radiated EMC testing at Herschel "EQM" level (AI H-P-ASPI-MN-406/10)
- □ HIFI RS in 4-8 GHz IF band
- Types of signals exchanged between Instrument units and
 - shielding/overshielding/shieldings connection strategies (backshells, etc.).
 - → Shield connection in balanced digital links
 - ➔ How to calculate SMA shielding?
 - Cryo-harness shields connections
- Grounding diagrams



Herschel-Planck

EMC/Power WG meeting #12 : actions review

			Action to	Status	Closure reference
Powe	r EMC	WG meeting #11 (H-P-ASPI-MN-306)			
AI1	:	Review LCL allocation and complete/correct	(Instruments)	OPEN / Partially CLOSED for HIFI	email from A. Naber
AI2	:	Provide EMC Control Plan	(SPIRE/PACS)	CLOSED for SPIRE	SPIRE-RAL-DOC-???
AI3	:	Provide EMC Control Plan	(LFI/HFI)	OPEN	
AI4	:	Comment HIFI EMC test results	(ASPI)	CLOSED	H-P-ASPI-LT-447
EMC V	NG m	eeting Herschel/Cryostat (H-P-ASPI-N-311)			
AI1	:	Provide details of DC resistance of waveguides	(HIFI)	OPEN	
AI2	:	Provide estimate of needs for SVM-CVV impedance	(HIFI)	OPEN	
AI3	:	Provide estimate of the electrical resistance of cryo harness	(Astrium)	CLOSED	HP-2-ASED-0090/01
AI4	to 7 :	Provide frequency plan	(SPIRE, PACS, ASPI+Alenia, Astrium)	CLOSED for Alenia and Astrium	HP-2-ASED-0090/01 email from E. Ciancetta
AI8	:	Explain how BOLA chassis is grounded	(PACS)	OPEN	
AI9	:	Evaluate ISO model for internal cryostat grounding	(Astrium)	CLOSED	HP-2-ASED-0090/01
AI10):	Identify (& provide) samples of ISO cryo cables	(ESA + Astrium)	Partially CLOSED for Astrium CLOSED for ESA (no samples)	HP-2-ASED-0090/01 email from B. Jackson
AI11	:	Identify (& provide) electrical models for cryo harness	(ESA + Astrium + ASPI)	Partially CLOSED	HP-2-ASED-0090/01
AI12	2 :	Provide overall grounding diagram	(ASPI)	OPEN	
Hersc	hel E	QM AIV meeting (H-P-ASPI-MN-406)			
AI11	:	To perform and circulate an evaluation of the EMC level inside cryostat"	(ASPI)	CLOSED	H-P-ASPI-LT-512



EMC/Power WG meeting #12 : Power

Clarification on LCL characteristics (Bob Hibberd)

Inrush current

- IID-A 2/0 section 5.9.5.6.4 : "Inrush current is limited by the spacecraft PDU LCL to a maximum of 1.5 times the short peak value. At LCL switch-on, the inrush current is limited by PDU LCL as well as the inductance in the user input circuit.
 - Inrush current is limited by the PDU LCL to a value between the instantaneous peak value and 1.5 times the instantaneous short peak value.
 - Inrush current duration is set [by?] the PDU LCL. To prevent LCL trip-off, users shall limit the inrush current duration to a maximum change [charge?] of 5A*msec (TBC).

LCL users shall limit the rate of change of inrush current to $1A/\mu s$."

Comments :

- → Text to be updated :
 - limitation of current slope to $1A/\mu$ s ensured by the LCL, not necessarily by the user alone
 - 5A*msec = 5 mC too high
- → Requirements on user inrush current at switch ON to be introduced in the § 5.14 EMC :
 - "plug-in" current specification (switch ON by an external relay)
 - inrush current specification (switch ON by an external LCL)



EMC/Power WG meeting #12 : Power

Inrush current (cont'd)

Plug-in current specification (switch ON with an external bounce-free relay set between the LISN and the user on the positive power line):

- → The recorded inrush current shall show the following 2 distinct aspects :
 - A plug-in current transient corresponding to the charge of the primary filter capacitors
 - A DC/DC converter start current transient
- → Plug-in current transient requirements :
 - S(l*dt) < **2 mC**
 - dl/dt < 2 A/µs
 - I peak < **30 A**
- → DC/DC converter start current transient requirements (TBC) :
 - shall not exceed the user line LCL current limitation value for a total time higher than (trip-off time / 2)
 - shall comply with : S(I*dt) < (LCL current limitation value)*(trip-off time / 2)



EMC/Power WG meeting #12 : Power

Inrush current (cont'd)

Inrush current specification (switch ON with an external LCL set between the LISN

and the user) :



A trip-off time / 2 = 5 ms (TBC) shall be assumed.



Herschel-Planck

EMC/Power WG meeting #12 : EMC

- Need and definition of <u>radiated</u> EMC testing at Herschel "EQM" level (AI H-P-ASPI-MN-406/10)
 - Extracts of Herschel EQM AIV meeting (1&2/10/2001) :



- → SPIRE : (slides) "An analysis of SPIRE verification requirements [...] has shown that we can do all the required testing at Instrument level, with the exception of [...] System level EMC testing - most especially radiative susceptibility tests [...] We would like therefore to carry out system tests in the EQM cryostat to complete the instrument verification for [...] EMC".
- The EMC environment in the cryostat has to be fully representative of the Herschel cryostat and demonstrated to be so by modelling or analysis".
- SPIRE is far more concerned about RFI corrupting the detection and readout circuit than in the more routine units on the SVM, Bolometers are sensitive to 1pW, RFI currents cause ohmic heating to the bolometers which becomes indistinguishabble to the readout circuit".
- (minutes) "If needed, the RF source shall be installed in the Herschel test cavity for RS testing".



- Need and definition of <u>radiated</u> EMC testing at Herschel "EQM" level (AI H-P-ASPI-MN-406/10) (cont'd)
 - Extracts of Herschel EQM AIV meeting (1&2/10/2001) :
 - → HIFI : (slides) "HIFI viewpoint regarding cQM tests [...] Test of conducted & radiated EMC is THE most useful aspect [...] Radiated most important [...]".
 - *Alcatel EQM objectives reviewed [...] THE most critical aspect for HIFI, radiated susceptibility, is not tested.

This will not be tested until Herschel FM is assembled. A problem discovered at that stage will be an **unmitigated disaster**.".

- "Proposed RS EMC Strategy : [...] either full RS EMC test of representative S/C
 [...] or
 - test/calculate shielding efficiency of cryostat" can be at room temp
 - determine RS sensitivity of HIFI FPU can be at room temp, HIFI AIV
 - combine the above to determine allowed EM field at the SVM
 - compare result with expected/measured EM field at the SVM

→ (minutes) "EMC [...] can be evaluated at room temperature

=> HIFI position = STM seems Ok !" (if no RS at EQM level is foreseen).



Need and definition of <u>radiated</u> EMC testing at Herschel "EQM" level (AI H-P-ASPI-MN-406/10) (cont'd)

Extracts of Herschel EQM AIV meeting (1&2/10/2001) :

PACS : (slides) "During ILT, two specific test sequences required for certain EMC measurements will be developed. During EQM, performance of these sequences will allow verification of certain EMC requirements. Note : EQM EMC testing might very likely require both types, conductive and radiative measurement (details TBC)".

→ Conclusion/Discussion : (minutes)

"The main open point are : Representativeness of the test set-up regarding EMC testing [...]".

"The baseline is to perform only CE and CS due to the expected shielding of the cryostat w.r.t. radiative environment [...] in bandwidth [10 kHz - 10 MHz]".

"Regarding radiated testing, the need and the definition shall be an outcome of the EMC working group".

"The implementation of this test shall be addressed by Astrium after the EMC WG decision".



AI H-P-ASPI-MN-406/11 (Herschel EQM AIV Meeting) : "to perform and circulate an evaluation of "EMC" level inside cryostat"





▼HIFI RS in 4-8 GHz IF band

Principle of RS relaxation from 2V/m to 2mV/m (66 dBµV/m) in IF band
 [3.5 - 9 GHz] agreed by ASPI and ESA, provided that the actual susceptibility thresholds are measured, should they be higher than 2mV/m.

Outcomes of EMC Implementation Assessment meeting (29-30/10/01, SRON-U) :

- ➔ Relaxation sufficient for HRS
- ➔ Relaxation sufficient for WBS
- → Relaxation may not be sufficient for FPU (IF signal susceptibility threshold =
 - -160 dBm), from B.J. v L. / P.J. d G. synthesis :
 - Negligible S.E. of cryostat
 - MSA S.E. limited by Optical and LO hole : S.E. \sim 5 dB
 - Mixer unit : tested AF \sim 67 dBm⁻¹ (for a particular mixer unit)

Give me a favor, use S.E. ! --- S.E. $(dB) = AF(dBm-1) + 20log\lambda - 19.76 \sim 21 dB$

- $P_{R}(dBm) = E(dB\mu V/m) SE(dB) + 10log(\lambda^{2}/4\pi) 115.76 =$ = 66 - 26 - 33.5 - 115.76 ~ -109 dBm : <u>roughly 50 dB are missing</u>
- → HIFI to go on considering possible improvements (+10 dB? +20 dB? +30 dB?)
- → ASPI and ESA to consider further relaxation and/or system margin reduction and/or analyses refinement



- Types of signals exchanged between Instrument units and shielding/overshielding/shieldings connection strategies (backshells, etc.).
 - Shield connection in balanced digital links :
 - → Alcatel advice :
 - connection of the STP shields to chassis at both ends
 - overshield not necessarily useful
 - → Standard practice on Alcatel Spacecraft's
 - → Limits radiated emission
 - → Limits impedance mismatching
 - How to calculate SMA shielding? (question from HIFI EMC Implementation Assessment meeting)
 - Cryo-harness shields connections
 - ➔ Technology ?
 - ➔ Backshells ?



Grounding diagrams

<u>Reminder</u> : Instruments were requested to use standard symbols presented at the last EMC WG meeting. Although it is understood that some more may be necessary (e.g. "analogue ground"), they should be limited to the minimum.

Problem common to all Instruments is protection of sensitive lines (detectors signals or bias lines) against common mode noise.

- LFI : draft was handed over by M. Miccolis at "LFI / HFI Satellite interfaces meeting" and commented
- IFI : the grounding diagram from IID-B does not include FPU → JFET → PAU → Analogue REU grounding (but presented in Instrument meeting). Bolometer detectors : possible synergy with Herschel/SPIRE ?

□ <u>HIFI</u> :

- → Clear grounding diagrams are available from IID-B
- Note "Filtering of FCU IF amplifiers interface", SRON-U/FCU/TN/2000-003, about to be updated with frequency dependant noise criterion



Herschel-Planck

EMC/Power WG meeting #12 : EMC

Grounding diagrams (cont'd)

SPIRE :

- Grounding diagram from IID-B 2.0 very dense and presenting dark zones (especially at DCU level) ...
- Grounding and screening philosophy" described in document from J. Delderfield, dated 3/04/2001: trade-off for bolometer "analogue ground" connection to chassis :
 - at BDA ? (via 300mK cold plumbing and sorption cooler straps)
 - at DCU ? ("analogue ground" at BDA isolated by sapphire)

(avoid ground loop to ensure low frequency common mode rejection)

"Computer grounding model" + test verifications expected to resolve trade-off

□ <u>PACS</u> :

- Grounding diagrams in "System Grounding Diagrams", PACS-ME-LI-006, Issue 1, 19/02/01 (to be annexed to IID-B), but does not include FPU grounding diagrams
- → Photoconductor (spectroscopy) FEE → DEC interconnection/grounding proposal presented at last meeting with lots of question marks. Also presented by Terence Bax on paper board. To be completed/confirmed and included in IID-B.
- → Bolometer (photometry) grounding diagram ?





Planck LFI EMC Control Plan

Document No.: PL-LFI-PST-PL-006 Issue/Rev. No.: 1.0 DRAFT Date: October 2001 Page:

1

1.1.1 Conducted Tests

Test Name	LFI	RAA	DAE	REBA	Note
Conducted Emission					
Power lines Diff. Mode NB	A	Т	Т	Т	
Power lines Comm. Mode NB	A	Т	Т	Т	
Power lines Diff. Mode Ripple Ampl.	A	Т	Т	Т	
Conducted Susceptibility					
Power lines Diff. Mode steady state	Т	Т	T	T	
Power lines Comm. Mode steady state	Т	T	Т	Т	
Signal lines Comm. Mode	Т	Т	Т	T	
Signal Ref. Comm. Mode steady state	Т	Т	Т	Т	
Signal lines Comm. Mode transient	Т	Т	Т	Т	
Power lines transient	Т	Т	Т	Т	

1.1.2 Radiated Tests

Test Name	LFI	RAA	DAE	REBA	Note
Radiated Emission					
E-Field NB	A	T	A	Т	
H-Field NB	A	T	A	Т	
Radiated Susceptibility					
E-Field NB	A	A	Т	Т	
H-Field NB	A	A	T	Т	

1.1.3 ESD Tests

Test Name	LFI	RAA	DAE	REBA	Note
Arc discharge Susceptibility					
ESD	A	A	Т	Т	



ANNEX III



3. Testing Approach

3.1 Configuration and Environments

	EQM	PFM	PFM
	Integrated Module	Integrated Module	Herschel
Configs:	 ISO Cryostat Flight Optical Bench Flight spare FPUs/Outer CVV electronic	 Full flight configuration	 Full flight
	and CVV instrumentation CVV inner cryo harness, el. representative CVV outer testharness, el. representative CVV Cover closed Avionics Modules (no SVM) No telescope, no sunshield/sunshade	except: - CVV cover closed - No Telescope - No sunshield/sunshade	configuration except: - CVV cover closed
Facility:	Cleanroom 100000	Cleanroom 100000	 Cleanroom Anechoic Chamber Cleanliness and impacts to be clarified for RS/RE tests
Operats:	 Reference RF/IR sources (tbd/tbc by INSTRUMENTS) ? 	Reference RF/IR sources (tbd/tbc by INSTRUMENTS) ?	•



3.2 Testing Baseline Proposal for EQM and PFM

	EQM Integrated Module	PFM Integrated Module	PFM Herschel
Tests:	 Conducted Tests: PLM CE (no test limits) on PLM units, primary power and secondary power PLM CS on PLM units, primary power 	 Conducted Tests: PLM CE (no test limits) on PLM units, primary power and secondary power PLM CS on PLM units, primary power 	 Conducted Tests: CE in general, inside satellite (no test limits)
	Radiated Tests: • none (X)	Radiated Tests: none	 Radiated Tests: RE E- and H-field, 14 kHz to 18 GHz RS (tbd PLM configurations)

(X): ASPI Requested to perform a "CS simulated RS" test or RS test

ASG :

- 1. RS test not in baseline proposal
- 2. "CS simulating RS" level prediction analysis not covered by baseline proposal (EMC spec was not issued/applicable for ASG proposal)
- 3. "CS simulating RS" test could be done (if the effort is in the frame expected for a standard CS test).



Discussion "CS simulating RS" Level Analysis vs. Standard RS Test for EQM Integrated Module

"CS simulating RS" Level Analysis: · Based on specified radiated environment, both for H-and E-field. \odot 6 dB margin to real field? Based on geometrical architecture/structure model (coupling loop length, \odot height) for the prediction of induced voltage Vi. 12 dB uncertainty ? Electrical modelling of harness, interfaces and structure: 12 dB uncertainty? $\overline{\ensuremath{\mathfrak{S}}}$ Easy and quick performance of test! \odot And, when the test fails? \odot Standard Module RS test FPUs somehow shielded from the CVV outer environment (H and E-field): Attenuation of CVV Structure (flight representative) Attenuation of Apertures (flight representative) Harness Couplings into CVV (flight representative) CVV cover closed (non-representative -----see "option"-----Avionics modules not flight representative with impact on RE (to be minimised not to influence the module \bigcirc RS results). • Anechoic chamber or specifically prepared integration site needed (absorbers, shields) -feasibility $(\mathbf{\dot{}})$ tbc/tbd



"Option": Specific Cryogenic Test Adapter

 can be put on a specific "MGSE" provided by the supplier of the cryostat cover (tbc) to test e.g. the opening and closing of the cryostat cover under vacuum conditions". This specific "MGSE" can be seen as EMC/electrical equivalent to the "straylight-trap" between telescope and CVV opening of HERSCHEL PFM.

- can be used on EQM only. The PFM will be equipped with the "straylight-trap" on which the adapter cannot be used due to mechanical reasons.
- contains a background cold mirror of (e.g.) solid AI, not to overdrive the FPUs during testing
- contains a "tuneable" blackbody (10K ... 300K) that could be removed (tbc/tbd) to increase

the

free-space in order to place a RF RS antenna or make the optical path to external antenna free (tbd).

The **Cryogenic Test Adapter** can/could be modified and/or re-built to fulfil the objectives of an RS test on the CVV interiors (FPUs and correlating CVV internal cryo harness)

ANNER IL



Ideas:

- use" of the a specific Cryogenic Test Adapter as needed for the Dark Background measurement, to
 - replace the black body by an antenna?
 - area available too small for a standard antenna
 - other types of quite small antennas operating in tbd Hz to tbd Hz?
 - remove the black body and use an specifically optical aperture in the adapter to couple RF in?
 - aperture diameter?
 - specific geometry of the cover for RF coupling purposes?
 - requirements on the cover from instruments side (field of view at tbc K)?
- "New" specific Cryogenic Test Adapter just for RS tests ?
 - place antenna in?
 - same points as from above
 - aperture in adapter
 - same points as above
- "Definitions" of environments and test
 - RS test levels (E-field, H-field, tbc) and frequencies
 - Fail/pass criteria and corresponding means necessary for calibration, alignment, data processing (quick-look)
 - specific CVV operations tbc
 - any restrictions

-DISCUSSION-

ANNEX IV





UPDATE REQUIRED



FPU-REU GROUNDING PHILOSOPHY UPDATE REQUIRED



Instrument Working Group September 27th -28th, 2001



Simulation Work - From bolometer to REU.



Dominique Yvon / CEA Saclay - SPP

EMC Modelling: Asymmetric Stray capacitance FET-BOX Grounding



20/02/2001

Dominique Yvon, CE Saclay/DAPNIA/SPP

Next Work in line: E Optimine HFI instrument grounding / Witting Design VS satellite EMI Model. => Obtain Satellite EMI Model (prefored) Obtain of build one from mechanical design of SVIT Then using simulations as a quide. Compromise with orgogenico_ Update design_





PLANCK LFI - Cryo-harness Thermal requirements

Source: Sorption Cooler Interface Control Document, Issue 3.3

VG3 @	50K	60K
FPU	7 + 14 mW	9 mW

Source: Herschel/Planck Instrument Interface Document, IID PART A, Issue 2.0

	Thermal load [mW]	Temperature [K]	Range [K]	Comments
VG3	100*	49	46 - 52	mean value
VG2	60*	98	56 - 101	worse case
VG1	730*	149	90 - 150	worse case

*: Values include 20% margin



PLANCK LFI - Cryo-harness Electric requirements (TBC)

FEM Connections	# wires
HEMT Drain	4 x 1 = 4
HEMT Gate 1	4 x 1 = 4
HEMT Gate 2	4 x 1 = 4
<pre></pre>	4 x 2 = 8
	1
HEMT GND	1
TOTAL	22



Wire	l max @ 20K	l max @ 300K	El. res. (W)	Total # wires
HEMT GND	40 mA	200 mA	< 1 Ω	27
HEMT Drain	10 mA	50 mA	< 5 Ω	108
<pre>ø switch</pre>	1 mA	1 mA	< 50 Ω	216
	4 mA	4 mA	< 10 Ω	27
HEMT Gate 1	100 µA	100 µA	< 1000 Ω	108
HEMT Gate 2	40 µA	40 µA	< 1000 Ω	108
Temp sensors	10 µA	10 µA	< 1000 Ω	48
TOTAL		·		642

A FINMECCANICA COMPANY

PLANCK LFI - Cryo-harness Routing philosophy

642 total wires to route from the BEU to the FEU:

- Separation of the different EMC classes
- 30 total cables:
 - 14 HEMT LNAs
 - 14 Phase Switches
 - 2 Temperature sensors

• HEMT LNAs and Phase Switch cables:

- 2 FEMs per cable, each 4 channels
- minimization of current paths
- trade-off: thermal and electric properties



PLANCK LFI - Cryo-Harness Routing Principle



PLANCK LFI - Cryo-harness Material selection for wires and shields

Materials for shielding	Thickness
Aluminium (Al)	100 nm
Gold (Au)	400 nm
Copper (Co)	250 nm

Materials for wires	Diameter
Aluminium (Al)	30 AWG 40 AWG
Gold (Au)	30 AWG 40 AWG
Phosphor-Bronze	30 AWG 40 AWG
Copper (Cu)	30 AWG 40 AWG
Nickel (Ni)	30 AWG 40 AWG
Platinum (Pt)	30 AWG 40 AWG
Titanium (Ti)	30 AWG 40 AWG
Constantan	30 AWG 40 AWG
Manganin	30 AWG 40 AWG



PLANCK LFI - Cryo-harness Mathematical model for the heat transfer estimation



 $\left(T_{j-1}-T_{j}\right)\cdot\boldsymbol{k}\left(T_{j,j-1}\right)\cdot\frac{Sec}{dx}+\left(T_{j+1}-T_{j}\right)\cdot\boldsymbol{k}\left(T_{j,j+1}\right)\cdot\frac{Sec}{dx}+\boldsymbol{r}\left(T_{j}\right)\cdot\frac{dx}{S}i^{2}+\boldsymbol{s}\cdot\boldsymbol{a}\cdot\left(T_{env}^{4}-T_{j}^{4}\right)=0$



PLANCK LFI - Cryo-harness Estimated temperature distribution

direct routing vs. VG3 interconnection



PLANCK LFI - Cryo-harness Thermal Optimum

Length (20-60K, 60-300K):	1.6m, 0.6m
Emissivity:	0.04
Coeff. of view (1=4PI):	0.6
Tenvironment (20-60K, 60-300K):	60K, 180K

			COLD PART: 20-60K			WARM	PART: 60)-300K
Wire	Current [A]	R _{TOT} [Ohm]	Material	AWG	P FPU	Material	AWG	P VG3
HEMT Drain	0.010000	5.0	Au	40	-7.40	Ni	40	-42.89
HEMT Gate	0.000100	194.5	Manganin	40	-0.76	Manganin	40	-14.29
Phase Switch	0.001000	63.0	Ti	38	-2.85	Manganin	40	-16.74
Phase Switch GND	0.004000	14.1	Pt	40	-1.06	PhBronze	40	-4.47
HEMT GND	0.040000	1.4	Au	34	-7.21	AI	38	-40.16
Temp. Sensors	0.000040	194.4	Manganin	40	-0.15	Manganin	40	-3.17
TOTAL					-19.44			-121.73
			Au	400 nm	-20.16	Au	400 nm	-131.44
TOTAL WITH SHIELD CONTRIBUTION		AI	100 nm	-20.39	AI	100 nm	-123.92	
			Cu	250 nm	-21.19	Cu	250 nm	-130.14

- Best possible thermal behavior in terms of heat transfer on FPU and VG3
- Thermal requirements are not satisfied for the case VG3 @ 60K
- Electric requirements are not satisfied
- Room temperature operation not allowed



PLANCK LFI - Cryo-harness Trade-Off Solution

Length (20-60K, 60-300K):	1.6m, 0.6m
Emissivity:	0.04
Coeff. of view (1=4PI):	0.6
Tenvironment (20-60K, 60-300K):	60K, 180K

			COLD	COLD PART: 20-60K			IPARI:	60-300K
Wire	Current [A]	R _{TOT} [Ohm]	Material	AWG	P _{FPU} [mW]	Materia	AWG	P _{VG3} [mW]
HEMT Drain	0.010000	2.71	Ni	38	-9.98	Ni	38	-57.43
HEMT Gate	0.000100	194.65	Manganin	40	-0.85	Manganin	40	-16.37
Phase Switch	0.001000	24.02	Ti	38	-3.07	Ti	38	-35.17
Phase Switch GND	0.004000	5.95	Ti	32	-1.31	Ti	32	-13.65
HEMT GND	0.040000	0.82	Cu	38	-9.29	Cu	38	-48.71
Temp. Sensors	0.000040	194.50	Manganin	40	-0.17	Manganin	40	-3.63
TOTAL					-24.67			-174.96
			Au	400 nm	-25.39	Au	400 nm	-184.67
TOTAL WITH SHIEL	D CONTRIBUT	ΓΙΟΝ	AI	100 nm	-25.62	AI	100 nm	-177.15
			Cu	250 nm	-26.42	Cu	250 nm	-183.37

A FINMECCANICA COMPANY

- Fulfillment of electrical requirements
- Room temperature operation allowed with additional high-emissivity coating
- Slight increase of the heat transfer on the FPU

PLANCK LFI - Cryo-harness Interconnection to VG's

Routing method	P _{FPU} [mW]	P _{VG3} [mW]	P _{VG2} [mW]	P _{VG1} [mW]
ID1: direct routing, no rad,I	50	-	-	-
ID6: direct routing, detailed env.	54	-	-	-
ID2: VG3, no rad,I	21	104	-	-
ID3: VG3, no rad	27	145	-	-
ID4: VG3	26	112	-	-
ID5: VG3 (60K), detailed env.	26	133	-	-
ID9: VG3, detailed env. (Alcatel: vg1=149K, vg2=98K, vg3=49K)	23	146	-	-
ID10: VG1, VG2, VG3, detailed env. (Alcatel: vg1=149K, vg2=98K, vg3=49K) 21	91	31	182
ID11: VG1, VG3, detailed env. (Alcatel: vg1=149K, vg2=98K, vg3=49K)	22	105		196

Estimated results without margin

A 20% margin should be foreseen due to the high sensitivity of the thermal model to the boundary conditions.



PLANCK LFI - Cryo-harness

Proposed technology for cryo-harness manufacturing

- 2.2 m cable length, 30 total cables.
- Selection of proper materials/gauges for the wires (trade-off thermal and electrical characteristics), according to the current flowing in the wires.
- Separation of the wires in two EMC classes (HEMT bias and Phase switch bias).
- Realisation of a thin shield (good conductor) through chemical vapor deposition.
- High-robustness Kapton coating of the cables for mechanical stability of the shield.



PLANCK LFI - Cryo-harness Summary of EMC aspects

Problems	Comments
Influence of external magnetic fields	Wire twisting not possible due to bias supply architecture and cable complexity
limited shielding effect	Need of trade-off thermal and electrical characteristics
reduced wire gauges, selected on the base of the flowing current	Current limitation on the voltage regulators (higher complexity)
possible charging effects of the Kapton coating (to be investigated)	Evaluation of discharge mechanisms and their influence on the wires

